

T-41-73

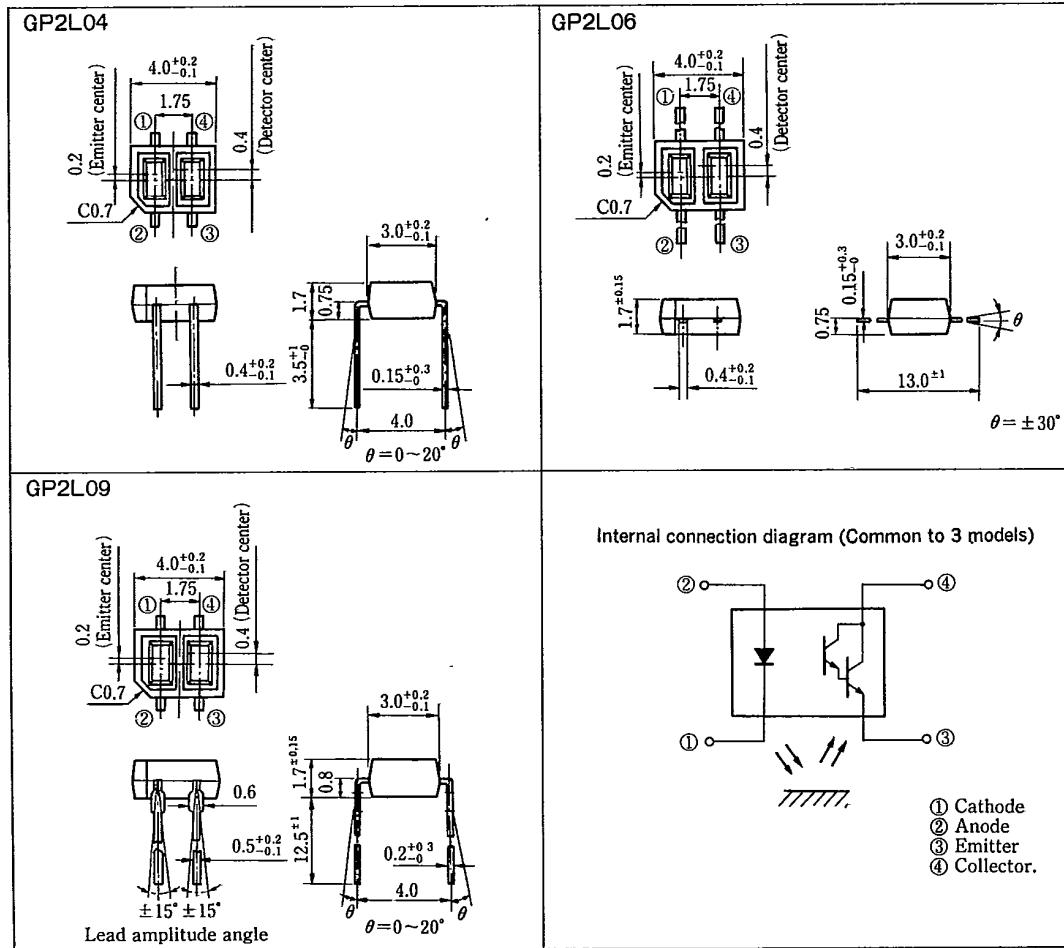
GP2L04/GP2L06 /GP2L09

Subminiature, High Sensitivity
Photointerrupter

■ Features

1. Compact and thin
GP2L04: Compact DIP type
GP2L06: Flat lead type
GP2L09: Compact DIP, long lead type
2. Optimal detection distance: 0.8~1mm
3. High sensitivity
(I_c : MIN. 0.5mA at $I_F = 4\text{mA}$)
4. Visible light cut-off type

■ Outline Dimensions



15E D 8180798 0003337 7

Photointerrupters

SHARP ELEK/ MELEC DIV

GP2L04/GP2L06/GP2L09

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Absolute Maximum Ratings

(Ta=25°C)

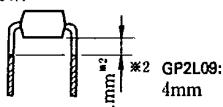
Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Reverse voltage	V _R	6	V
	Power dissipation	P _D	75	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECD}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	75	mW
Total power dissipation		P _{tot}	100	mW
Operating temperature		T _{opr}	-25 ~ +85	°C
Storage temperature		T _{stg}	-40 ~ +100	°C
*1 Soldering temperature		T _{sol}	260	°C

*1 Within 5 seconds (Soldering areas are shown below.)

GP2L04, GP2L09

Soldering area

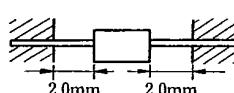
The hatched area more than 1mm*2 away from the lower edge of package as shown in the drawing below.



GP2L06

Soldering area

The hatched area more than 2.0mm away from the both edges of package as shown in the drawing below.

**Electro-optical Characteristics**

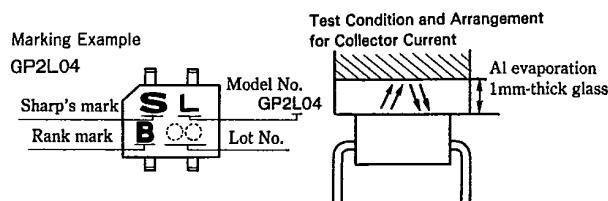
(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F =20mA	—	1.2	1.4	V
	Reverse current	I _R	V _R =6V	—	—	10	μA
Output	Collector dark current	I _{CEO}	V _{CE} =10V, I _F =0	—	—	1×10 ⁻⁶	A
Transfer characteristics	*3 Collector current	I _C	V _{CE} =2V, I _F =4mA	0.5	3.0	15.0	mA
	Response time (Rise)	t _r	V _{CE} =2V, I _C =10mA	—	80	400	μs
	Response time (Fall)	t _f	R _L =100Ω	—	70	400	μ
	*4 Leak current	I _{LEAK}	I _F =4mA, V _{CE} =5V	—	—	5.0	μA

*3 The condition and arrangement of the reflective object are shown in the right drawing.

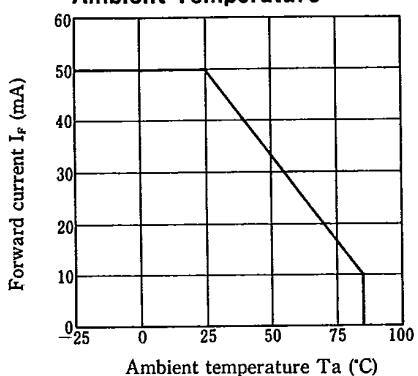
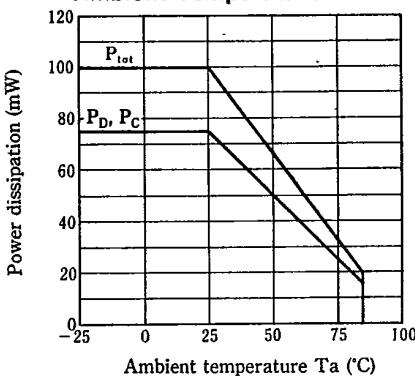
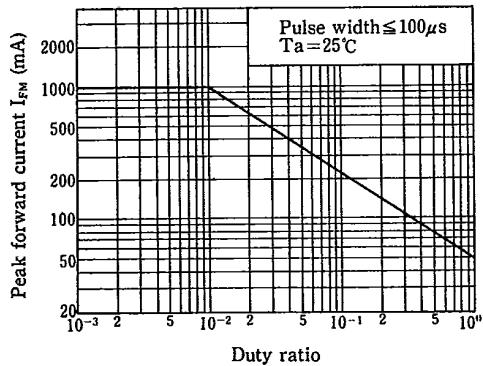
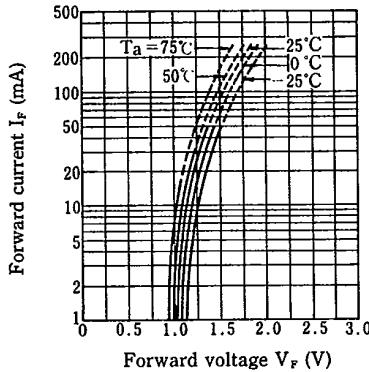
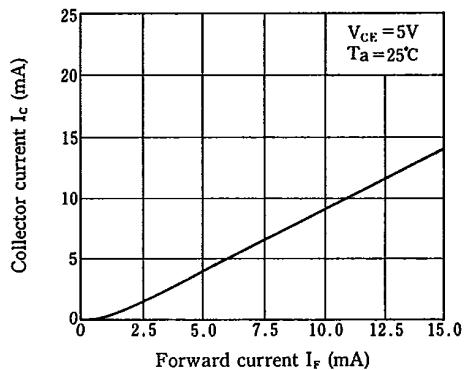
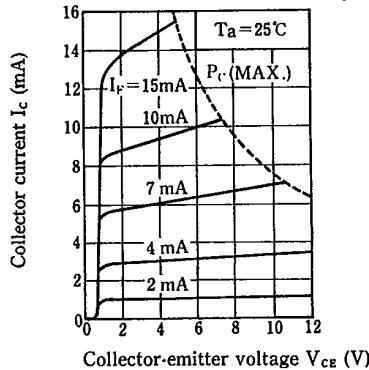
*4 Without reflective object

Rank	I _C (mA)	Rank mark
A	0.5~1.9	A
B	1.45~5.4	B
C	4.0~15.0	C
AB	0.5~5.4	A or B
BC	1.45~15.0	B or C
ABC	0.5~15.0	A, B or C

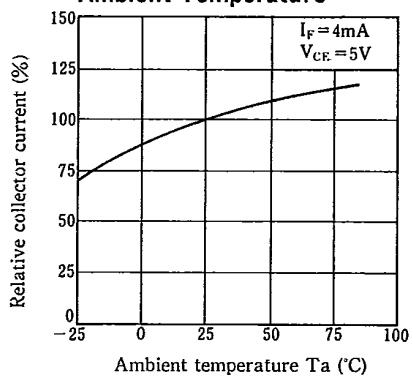
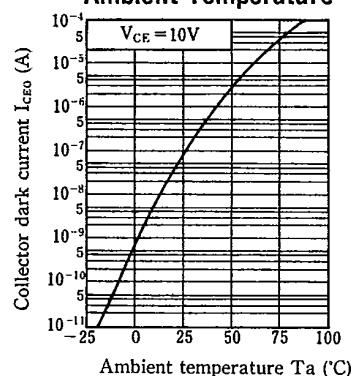
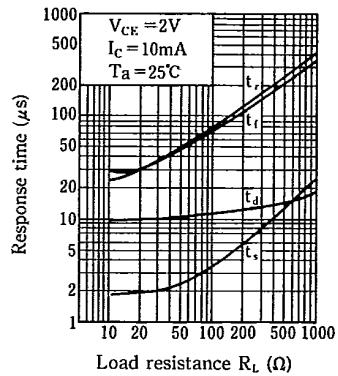
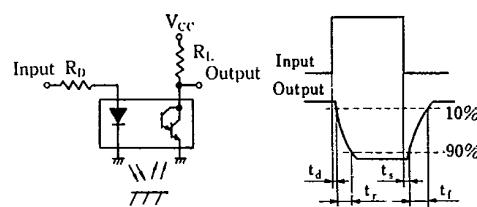


SHARP

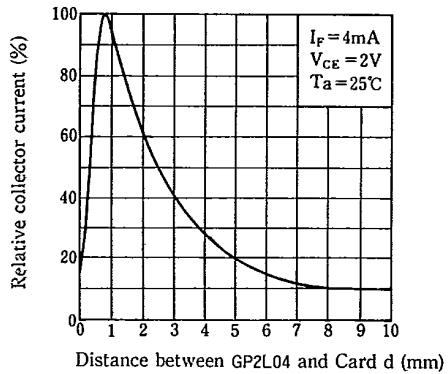
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Fig. 1 Forward Current vs. Ambient Temperature**Fig. 2 Power Dissipation vs. Ambient Temperature****Fig. 3 Peak Forward Current vs. Duty Ratio****Fig. 4 Forward Current vs. Forward Voltage****Fig. 5 Collector Current vs. Forward Current****Fig. 6 Collector Current vs. Collector-emitter Voltage**

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Fig. 7 Relative Collector Current vs. Ambient Temperature**Fig. 8 Collector Dark Current vs. Ambient Temperature****Fig. 9 Response Time vs. Load Resistance****Test Circuit for Response Time**

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Fig. 10 Relative Collector Current vs. Distance between GL2L04 and Card**Fig. 11 Relative Collector Current vs. Card Moving Distance (1)**